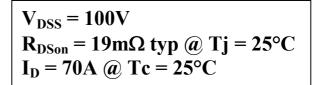
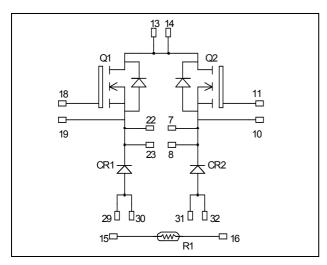
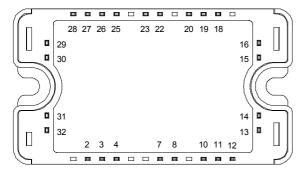


Dual Buck chopper MOSFET Power Module







All multiple inputs and outputs must be shorted together Example: 13/14; 29/30; 22/23 ...

Application

- AC and DC motor control
- Switched Mode Power Supplies

Features

- Power MOS V® MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- Each leg can be easily paralleled to achieve a single buck of twice the current capability
- RoHS Compliant

Absolute maximum ratings

INSUIUL	c maximum ratings			
Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		100	V
Ţ	Continuous Dusin Comment	$T_c = 25$ °C	70	
I_D	Continuous Drain Current	$T_c = 80$ °C	50	A
I_{DM}	Pulsed Drain current		300	
V_{GS}	Gate - Source Voltage		±30	V
R_{DSon}	Drain - Source ON Resistance		21	mΩ
P_{D}	Maximum Power Dissipation	$T_c = 25^{\circ}C$	208	W
I_{AR}	Avalanche current (repetitive and non repetitive)		75	Α
E_{AR}	Repetitive Avalanche Energy		30	mJ
E _{AS}	Single Pulse Avalanche Energy		1500	IIIJ

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 100V$	$T_j = 25^{\circ}C$			250	^
		$V_{GS} = 0V, V_{DS} = 80V$	$T_{j} = 125^{\circ}C$			1000	μA
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 35A$			19	21	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 1 \text{mA}$		2		4	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$	V			±100	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		5100		
C_{oss}	Output Capacitance	$V_{DS} = 25V$		1900		pF
C_{rss}	Reverse Transfer Capacitance	f = 1MHz		800		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		200		
Q_{gs}	Gate – Source Charge	$V_{\text{Bus}} = 100 \text{V}$		40		nC
Q_{gd}	Gate – Drain Charge	$I_D = 70A$		92		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		35		
T_{r}	Rise Time	$V_{GS} = 15V$		70		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 66V$ $I_{\text{D}} = 70A$		95		ns
T_{f}	Fall Time	$R_G = 5\Omega$		125		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		276		1
E_{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 70A, R_G = 5\Omega$		302		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		304		I
E _{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 70A, R_G = 5\Omega$		320		μJ

Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions	Test Conditions		Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			200			V
T	Maximum Reverse Leakage Current V _P =200V ⊢	V -200V	$T_j = 25$ °C			250	^
I_{RM}		$T_{j} = 125^{\circ}C$			500	μA	
I_F	DC Forward Current		Tc = 80°C		60		A
	Diode Forward Voltage	$I_F = 60A$			1.1		
V_{F}		$I_F = 120A$			1.4		V
		$I_F = 60A$	$T_i = 125$ °C		0.9		
t		I (0.4	$T_j = 25$ °C		31		ns
·rr		$I_F = 60A$ $V_R = 133V$	$T_{j} = 125^{\circ}C$		60		115
Qrr	Reverse Recovery Charge	$di/dt = 200 A/\mu s \qquad T_j = 25^{\circ} C$	$T_j = 25$ °C		60		nC
			$T_{j} = 125^{\circ}C$		250		IIC.



Thermal and package characteristics

Symbol	Characteristic			Min	Typ	Max	Unit
D	Lunction to Case Thermal Resistance	7	Transistor			0.6	°C/W
R_{thJC}		Diode			0.9	C/ W	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature					100	
Torque	Mounting torque	To heatsin	k M4	2		3	N.m
Wt	Package Weight					110	g

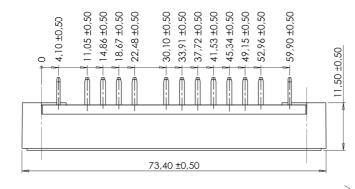
Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

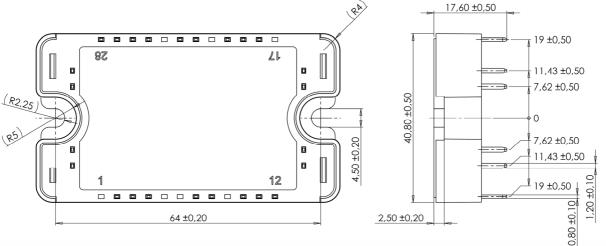
Symbol	Characteristic	Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
B _{25/85}	$T_{25} = 298.15 \text{ K}$		3952		K

$$R_{T} = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

$$R_{T}: \text{ Thermistor value at T}$$

SP3 Package outline (dimensions in mm)

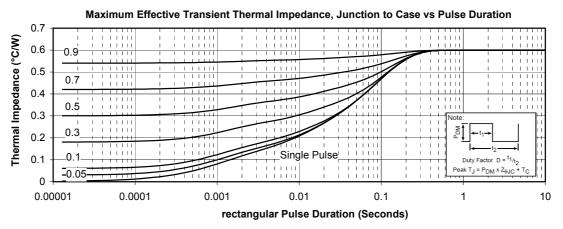


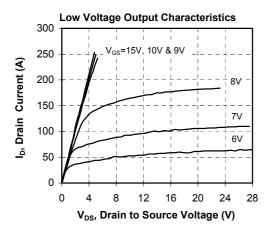


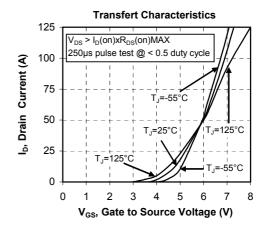
See application note 1901 - Mounting Instructions for SP3 Power Modules on www.microsemi.com

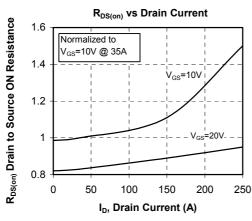


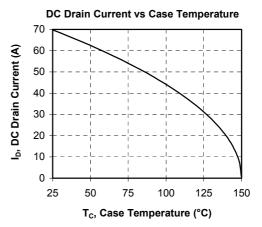
Typical Performance Curve



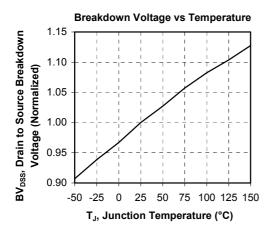


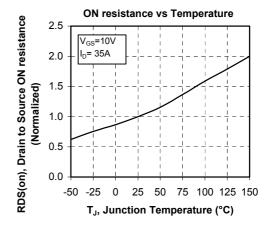


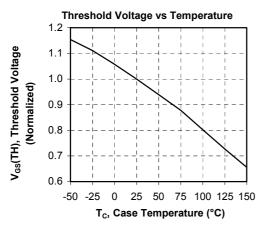


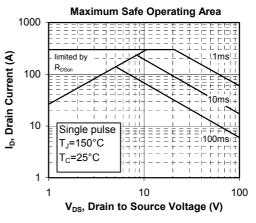


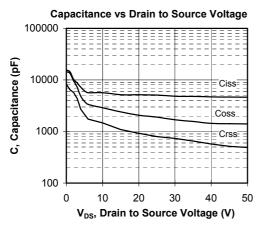


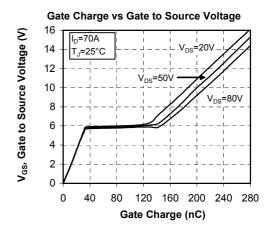




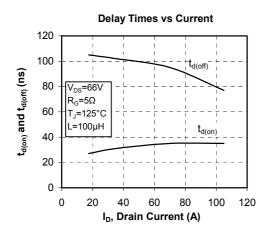


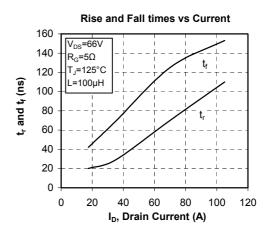


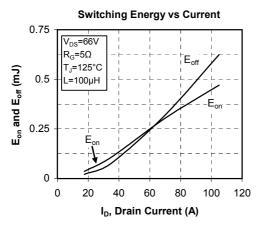


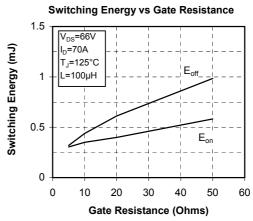


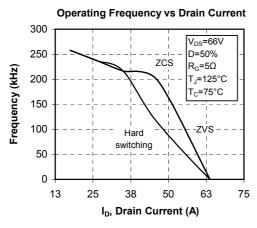


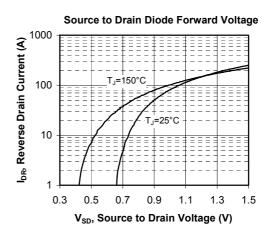












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